PNP -5.0A -30V Middle Power Transistor

Parameter	Value
V _{CEO}	-30V
I _C	-5A

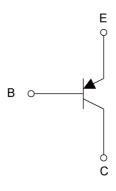
Outline



Features

- 1) Suitable for Middle Power Driver.
- 2) Complementary NPN Types: 2SCR572D.
- 3) Low $V_{CE(sat)}$ $V_{CE(sat)}$ =-0.40V(Max.). (I_C/I_B =-2A/-100mA)
- 4) Lead Free/Rohs Compliant

•Inner circuit



B: BASE

C: COLLECTOR

E: EMITTER

Application

Motor driver, LED driver

Power supply

Packaging specifications

Part No.	Package	Package size	Taping code	Reel size (mm)	Tape width (mm)	Basic ordering unit.(pcs)	Marking
2SAR572D	CPT	6595	TL	330	16	2500	AR572

● Absolute maximum ratings (T_a = 25°C)

Parameter	Symbol	Values	Unit
Collector-base voltage	V_{CBO}	-30	V
Collector-emitter voltage	V _{CEO}	-30	V
Emitter-base voltage	V _{EBO}	-6	V
Collector current	I _C	-5	Α
Collector current	I _{CP} *1	-10	Α
Base current	I _B	-1.5	Α
Power dissipation	P _D *2	10	W
Junction temperature	T _j	150	°C
Range of storage temperature	T _{stg}	-55 to +150	°C

● Electrical characteristics (T_a = 25°C)

Doromator	Symbol	Conditions	Values			Lloit
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Collector-base breakdown voltage	BV_CBO	I _C = -100μA	-30	-	ı	V
Collector-emitter breakdown voltage	BV _{CEO}	I _C = -1mA	-30	-	ı	V
Emitter-base breakdown voltage	BV_{EBO}	I _E = -100μA	-6	-	-	V
Collector cut-off current	I _{CBO}	V _{CB} = -30V	-	-	-1	μA
Emitter cut-off current	I _{EBO}	V _{EB} = -4V	-	-	-1	μA
Collector-emitter saturation voltage	V _{CE(sat)}	$I_C = -2A$, $I_B = -100mA$	-	-200	-400	mV
DC current gain	h _{FE}	$V_{CE} = -3V, I_{C} = -500 \text{mA}$	200	-	500	-
Transition frequency	f _T *3	V _{CE} = -10V, I _E = 200mA, f = 100MHz	-	300	-	MHz
Output capacitance	C_ob	$V_{CB} = -10V$, $I_E = 0A$, $f = 1MHz$	-	40	-	pF
Turn-On time	t _{on} *4	I _C = -2.5A, V _{CC} = -10V	-	80	-	ns
Storage time	t _{stg} *4	I _{B1} = -250mA	-	400	-	ns
Fall time	t _f *4	I _{B2} = 250mA	-	200	-	ns

^{*1} Pw=10ms 1PULSE

^{*2} Tc=25℃

^{*3} PULSED

^{*4} SEE SWITCHING TIME TEST CIRCUIT

● Electrical characteristic curves(T_a = 25°C)

Fig.1 Grounded Emitter Propagation Characteristics

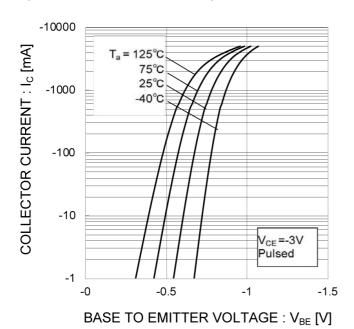
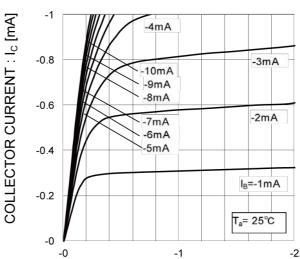


Fig.2 Typical Output Characteristics



COLLECTOR TO EMITTER VOLTAGE: V_{CE} [V]

Fig.3 DC Current Gain vs. Collector Current(I)

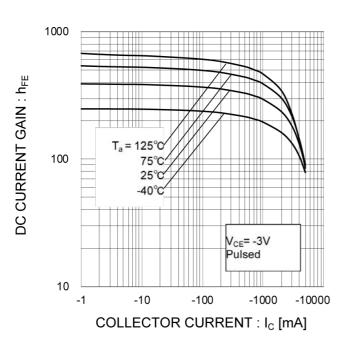
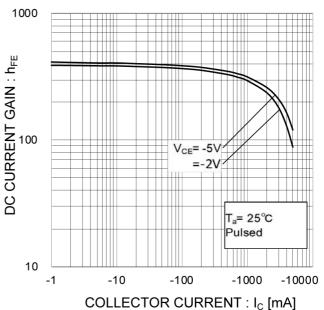


Fig.4 DC Current Gain vs. Collector Current(II)



● Electrical characteristic curves(T_a = 25°C)

Fig.5 Collector-Emitter Saturation Voltage vs. Collector Current(I)

COLLECTOR-EMITTER

Logical SATURATION VOLTAGE ... $V_{\text{C}}(s_{\text{Sat}})$ [N]

-0.01

-0.01

-0.01

-1

-1

-10

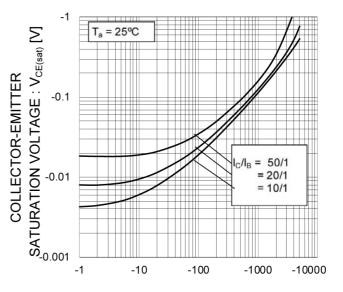
-1000

-10000

-10000

COLLECTOR CURRENT: Ic [mA]

Fig.6 Collector-Emitter Saturation Voltage vs. Collector Current(II)



COLLECTOR CURRENT: Ic [mA]

Fig.7 Base-Emitter Saturation Voltage vs. Collector Current

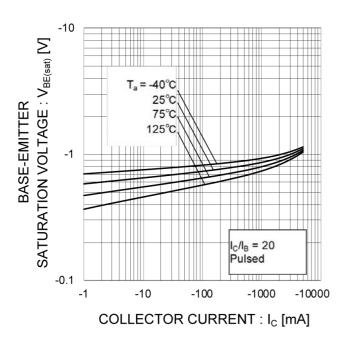
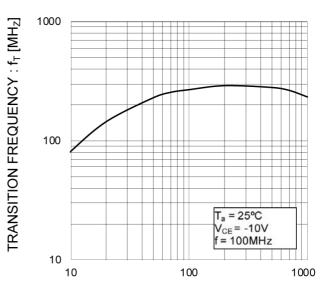


Fig.8 Gain Bandwidth Product vs. Emitter Current



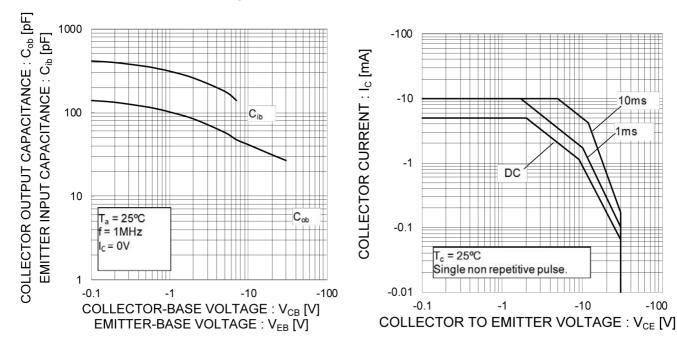
EMITTER CURRENT : IE [mA]

10ms

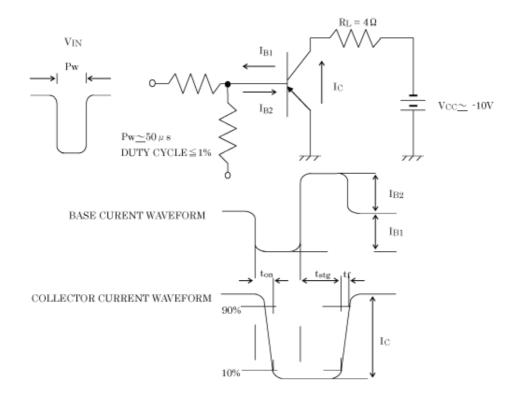
● Electrical characteristic curves(T_a = 25°C)

Fig.9 Emitter input capacitance vs. Emitter-Base Voltage Collector output capacitance vs. Collector-Base Voltage

Fig.10 Safe Operating Area

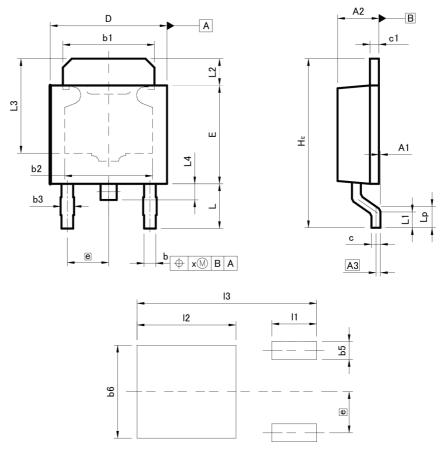


SWITCHING TIME TEST CIRCUIT



Dimensions

CPT



Pattern of terminal position areas [Not a recommended pattern of soldering pads]

DIM	MILIM	ETERS	INCHES		
DIM	MIN	MAX	MIN	MAX	
A1	0.00	0.15	0.000	0.006	
A2	2.20	2.50	0.087	0.098	
A3	0.	25	0.010		
b	0.55	0.75	0.022	0.030	
b1	5.00	5.30	0.197	0.209	
b2	5.	00	0.1	97	
b3		75	0.0	30	
С	0.40	0.60	0.016	0.024	
c1	0.40	0.60	0.016	0.024	
D	6.30	6.70	0.248	0.264	
E	5.40	5.80	0.213	0.228	
е	2.30		0.091		
HE	9.00	10.00	0.354	0.394	
L	2.20	2.80	0.087	0.110	
L1	0.80	1.40	0.031	0.055	
L2	1.20	1.80	0.047	0.071	
L3	5.30		0.209		
L4	0.90		0.035		
Lp	1.00	1.60	0.039	0.063	
X		0.25	-	0.010	

DIM	MILIM	ETERS	INCHES	
	MIN	MAX	MIN	MAX
b5		1.00	3-	0.04
b6	-	5.20	-	0.205
11	-	2.50	2.4	0.098
12	_	5.50		0.217
13		10.00	- 2	0.394

Dimension in mm/inches



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